	AEC-	·Q200	Specifications						
No.		Item	Temperature Compensating Type	High Dielectric Type	AEC-Q200 Test Method				
1	Pre-and Post-Stress Electrical Test		-		-				
	High Temperature Exposure (Storage)		The measured and observed characteristics should satisfy the specifications in the following table.						
		Appearance	No marking defects						
2		Capacitance Change	Within ±2.5% or ±0.25pF (Whichever is larger)	Within ±10.0%	Sit the capacitor for 1000±12 hours at 150±3°C. Let sit for 24±2				
_		Q/D.F.	30pFmin.: Q≧1000 30pFmax.: Q≥400+20C C: Nominal Capacitance (pF)	*1 W.V.: 25Vmin.: 0.03 max. W.V.: 16V: 0.05 max.	hours at room temperature, then measure.				
		I.R.	More than 10,000M Ω or 500 Ω · (Whichever is smaller)	F *1					
	Temperati Cycle	ture	The measured and observed characteristics should satisfy the specifications in the following table.		Fix the capacitor to the supporting jig in the same manner and under the same conditions as (18). Perform the 1000 cycles				
		Appearance	No marking defects		according to the four heat treatments listed in the following table. Let sit for 24±2 hours at room temperature, then measure				
		Capacitance Change	Within ±2.5% or ±0.25pF (Whichever is larger)	Within ±10.0%	Step 1 2 3 4				
3		Q/D.F.	30pFmin.: Q≥1000 30pFmax.: Q≥400+20C C: Nominal Capacitance (pF)	*1 W.V.: 25Vmin.: 0.03 max. W.V.: 16V: 0.05 max.	Time (min.) 15±3 1 15±3 1				
		I.R.	More than 10,000M Ω or 500 Ω · F (Whichever is smaller)		 Initial measurement for high dielectric constant type Perform a heat treatment at 150⁺⁰/₀°C for one hour and then let sit for 24±2 hours at room temperature. Perform the initial measurement. 				
4	Destructi Physical		No defects or abnormalities		Per EIA-469				
	Moisture Resistance		The measured and observed characteristics should satisfy the specifications in the following table.		Apply the 24-hour heat (25 to 65°C) and humidity (80 to 98%) treatment shown below, 10 consecutive times.				
		Appearance	No marking defects		Let sit for 24±2 hours at room temperature, then measure.				
		Capacitance Change	Within ±3.0% or ±0.30pF (Whichever is larger)	Within ±12.5%	Humidity Humidity Humidity Humidity C 90-98% 80-98% 90-98% 80-98% 90-98% 70				
5		Q/D.F.	30pFmin.: Q≥350 10pF and over, 30pF and below: Q≥275+ ½ C 10pFmax.: Q≥200+10C C: Nominal Capacitance (pF)	*1 W.V.: 25Vmin.: 0.03 max. W.V.: 16V: 0.05 max.	65 60 65 50 45 40 91 35 80 30 62 25				
	l.R.		More than 10,000M Ω or 500 Ω · F (Whichever is smaller)		One cycle 24 hours 0 1 2 3 4 5 6 7 8 9 101112131415161718192021222324 Hours				
	Biased H	umidity	The measured and observed characteristics should satisfy the specifications in the following table.						
		Appearance	No marking defects						
6		Capacitance Change	Within ±3.0% or ±0.30pF (Whichever is larger)	Within ±12.5%	Apply the rated voltage and 1.3+0.2/-0Vdc (add 6.8k Ω resistor) at 85±3°C and 80 to 85% humidity for 1000±12 hours. Remove and let sit for 24±2 hours at room temperature, then				
υ		Q/D.F.	30pF and over: Q≥200 30pF and below: Q≥100+ ¹⁰ / ₃ C C: Nominal Capacitance (pF)	*1 W.V.: 25Vmin.: 0.035 max. W.V.: 16V: 0.05 max.					
		I.R.	More than 1,000M Ω or 50 Ω · F (Whichever is smaller)	*1					

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N.	AEC-	Q200	Specifi	cations	AFO COOO To at Mark and		
No.	Test		Temperature Compensating Type	High Dielectric Type	AEC-Q200 Test Method		
7	Operational Life		The measured and observed characteristics should satisfy the specifications in the following table.				
		Appearance	No marking defects		Apply 200% of the rated voltage for 1000±12 hours at		
		Capacitance Change	Within ±3.0% or ±0.30pF (Whichever is larger)	Within ±12.5%	125±3°C. Let sit for 24±2 hours at room temperature, then measure. *2 The charge/discharge current is less than 50mA.		
		Q/D.F.	30pFmin.: Q≧350 10pF and over, 30pF and below: Q≥275+ ½ C 10pFmax.: Q≥200+10C C: Nominal Capacitance (pF)	*1 W.V.: 25Vmin.: 0.035 max. W.V.: 16V: 0.05 max.			
		I.R.	More than 1,000M Ω or 50 Ω · F (Whichever is smaller)	*1			
8	External	/isual	No defects or abnormalities		Visual inspection		
9	Physical [Dimension	Within the specified dimensions		Using calipers		
		Appearance	No marking defects		Per MIL-STD-202 Method 215		
		Capacitance Change	Within the specified tolerance		Solvent 1: 1 part (by volume) of isopropyl alcohol 3 parts (by volume) of mineral spirits		
10	Resistance to Solvents	Q/D.F.	30pFmin.: Q≥1000 30pFmax.: Q≥400+20C C: Nominal Capacitance (pF)	*1 W.V.: 25Vmin.: 0.025 max. W.V.: 16V: 0.035 max.	Solvent 3: 42 parts (by volume) of water 1 part (by volume) of propylene glycol		
		I.R.	More than 10,000M Ω or 500 Ω · (Whichever is smaller)	F *1	monomethylether 1 part (by volume) of monoethanolomine		
		Appearance	No marking defects				
	Mechanical Shock	Capacitance Change	Within the specified tolerance		Three shocks in each direction should be applied along 3		
11		Q/D.F.	30pFmin.: Q≧1000 30pFmax.: Q≧400+20C C: Nominal Capacitance (pF)	*1 W.V.: 25Vmin.: 0.025 max. W.V.: 16V: 0.035 max.	mutually perpendicular axes of the test specimen (18 shocks). The specified test pulse should be Half-sine and should have a duration: 0.5ms, peak value: 1500g and velocity change: 4.7m/s.		
		I.R.	More than 10,000M Ω or 500 Ω · (Whichever is smaller)	F *1			
		Appearance	No defects or abnormalities		Solder the capacitor to the test jig (glass epoxy board) in the		
		Capacitance Change	Within the specified tolerance		same manner and under the same conditions as (19). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied		
12	Vibration	Q/D.F.	30pFmin.: Q≧1000 30pFmax.: Q≧400+20C C: Nominal Capacitance (pF)	*1 W.V.: 25Vmin.: 0.025 max. W.V.: 16V: 0.035 max.	uniformly between the approximate limits of 10 and 2000Hz. The frequency range, from 10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be		
		I.R.	More than 10,000M Ω or 500 Ω · (Whichever is smaller)	F *1	applied for 12 items in each 3 mutually perpendicular direction (total of 36 times).		
	Resistance to Soldering Heat Appearance Capacitance Change		The measured and observed characteristics should satisfy the specifications in the following table. No marking defects				
13					 Immerse the capacitor in a eutectic solder solution at 260±5°C for 10±1 seconds. Let sit at room temperature for 24±2 hours, then 		
			Within the specified tolerance		measure.		
		Q/D.F.	30pFmin.: Q≥1000 30pFmax.: Q≥400+20C C: Nominal Capacitance (pF)	*1 W.V.: 25Vmin.: 0.025 max. W.V.: 16V: 0.035 max.	 Initial measurement for high dielectric constant type Perform a heat treatment at 150⁺⁰/₁₀°C for one hour and then le sit for 24±2 hours at room temperature. Perform the initial measurement. 		
		I.R.	More than $10,000M\Omega$ or 500Ω · (Whichever is smaller)	F *1			

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M.	AEC-	Q200	Specifi	cations	AFO COMO Tarak Madhard			
No.	Test	Item	Temperature Compensating Type	High Dielectric Type	AEC-Q200 Test Method			
14	Thermal Shock		The measured and observed characteristics should satisfy the specifications in the following table.		Fix the capacitor to the supporting jig in the same manner and under the same conditions as (18). Perform the 300 cycles			
	Appearance		No marking defects		according to the two heat treatments listed in the following table (Maximum transfer time is 20 seconds). Let sit for 24±2 hours a			
		Capacitance Change	Within ±2.5% or ±0.25pF (Whichever is larger)	Within ±10.0%	room temperature, then measure. Step 1 2			
		Q/D.F.	30pF min.: Q≥1000 30pF max.: Q≥400+20C C: Nominal Capacitance (pF)	*1 W.V.: 25Vmin.: 0.025 max. W.V.: 16V: 0.035 max.	Temp. (°C) -55+0/-3 125+3/-0 (5C, C7, R7) Time (min.) 15±3 15±3 15±3			
		I.R.	More than 10,000M Ω or 500 Ω · F (Whichever is smaller)		Perform a heat treatment at 150 ^{±0} ₁₀ °C for one hour and then let sit for 24±2 hours at room temperature. Perform the initial measurement.			
		Appearance	No marking defects					
		Capacitance Change	-					
15	ESD	Q/D.F.	30pF min.: Q≧1000 30pF max.: Q≥400+20C C: Nominal Capacitance (pF)	*1 W.V.: 25Vmin.: 0.025 max. W.V.: 16V: 0.035 max.	Per AEC-Q200-004			
		I.R.	More than 10,000M Ω or 500 Ω · (Whichever is smaller)	F *1				
16	Solderability				(a) Preheat at 155°C for 4 hours. After preheating, immerse the capacitor in a solution of ethanol (JIS-K-8101) and rosin (JIS-K-5902) (25% rosin in weight proportion). Immerse in eutectic solder solution for 5+0/-0.5 seconds at 235±5°C.			
			95% of the terminations is to be continuously.	soldered evenly and	(b) Should be placed into steam aging for 8 hours±15 minutes. After preheating, immerse the capacitor in a solution of ethanol (JIS-K-8101) and rosin (JIS-K-5902) (25% rosin in weight proportion). Immerse in eutectic solder solution for 5+0/-0.5 seconds at 235±5°C.			
					(c) Should be placed into steam aging for 8 hours±15 minutes. After preheating, immerse the capacitor in a solution of ethanol (JIS-K-8101) and rosin (JIS-K-5902) (25% rosin in weight proportion). Immerse in eutectic solder solution for 12 ±5 seconds at 260±5°C.			
		Appearance	No defects or abnormalities		Visual inspection.			
		Capacitance Change	Within the specified tolerance		The capacitance/Q/D.F. should be measured at 25°C at the frequency and voltage shown in the table.			
17	Electrical Chatacteri- zation	Q/D.F.	30pF min.: Q≥1000 30pF max.: Q≥400+20C C: Nominal Capacitance (pF)	*1 W.V.: 25V min.: 0.025 max. W.V.: 16V: 0.035 max	(1) Temperature Compensating Type Capacitance Frequency Voltage			
		I.R.	25°C More than 100,000MΩ or 1,000Ω · F (Whichever is smaller) Max. Operating Temperature125°C More than 10,000MΩ or 100Ω · F (Whichever is smaller)	*1 25°C More than 10,000M Ω or 500 Ω · F (Whichever is smaller) Max. Operating Temperature···125°C More than 1,000M Ω or 10 Ω · F (Whichever is smaller)	The insulation resistance should be measured with a DC voltage not exceeding the rated voltage at 25°C and 125°C and within minutes of charging.			
		Dielectric Strength	No failure		No failure should be observed when 250% of the rated voltage is applied between the terminations for 1 to 5 seconds, provided the charge/discharge current is less than 50mA.			

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NI -	AEC-	Q200	Specifications		AEC 0200 Test Method				
No.	Test	Item	Temperature Compensating Type	High Dielectric Type	AEC-Q200 Test Method				
		Appearance	No marking defects		Solder the capacitor on the test jig (glass epoxy board) shown in				
		Capacitance Change	Within ±5.0% or ±0.5pF (Whichever is larger)	Within ±10.0%	Fig. 1 using a eutectic solder. Then apply a force in the direction shown in Fig. 2 for 5±1sec. The soldering should be done by the reflow method and should be conducted with care so that the				
		Q/D.F.	30pF min.: Q≥1000 *1 30pF max.: Q≥400+20C W.V.: 25Vmin.: 0.025 max.		soldering is uniform and free of defects such as heat shock.				
		Q/D.1.	C: Nominal Capacitance (pF)	W.V.: 16V: 0.035 max.	Type a b c GCM03 0.3 0.9 0.3				
18	Board Flex	I.R.	*1 More than 10,000MΩ or 500Ω · F (Whichever is smaller)	t: 1.6mm (GCM03/15: 0.8mm)	GCM15 0.5 1.5 0.6 GCM18 0.6 2.2 0.9 GCM21 0.8 3.0 1.3 GCM31 2.0 4.4 1.7 GCM32 2.0 4.4 2.6 (in mm) Pressunzing speed: 1.0mm/sec Pressurize Pressurize Flexure: ≤2 (High Dielectric Type) Flexure: ≤3 (Temperature Compensating Type) Fig. 2				
		Appearance	No marking defects		Solder the capacitor to the test jig (glass epoxy board) shown in Fig. 3 using a eutectic solder. Then apply *18N force in parallel				
		Capacitance Change	Within the specified tolerance		with the test jig for 60sec.				
		Q/D.F.	30pF min.: Q≥1000 30pF max.: Q≥400+20C C: Nominal Capacitance (pF)	*1 W.V.: 25Vmin.: 0.025 max. W.V.: 16V: 0.035 max.	The soldering should be done either with an iron or using the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock. *2N (GCM03/15)				
19	Terminal Strength	I.R.	*1 More than $10,000\text{M}\Omega$ or $500\Omega \cdot \text{F}$ (Whichever is smaller)		Type a b c GCM03 0.3 0.9 0.3 GCM15 0.4 1.5 0.5 GCM18 1.0 3.0 1.2 GCM21 1.2 4.0 1.65 GCM31 2.2 5.0 2.0 GCM32 2.2 5.0 2.9 (in mm)				
20	0 Beam Load Test		The chip endure following force. < Chip L dimension: 2.5mm max. > Chip thickness > 0.5mm rank: 20N Chip thickness ≤ 0.5mm rank: 8N < Chip L dimension: 3.2mm min. > Chip thickness < 1.25mm rank: 15N Chip thickness ≥ 1.25mm rank: 54.5N		Place the capacitor in the beam load fixture as Fig. 4. Apply a force. < Chip Length: 2.5mm max. > Iron Board Speed supplied the Stress Load: 0.5mm / sec. < Chip Length: 3.2mm min. > Speed supplied the Stress Load: 2.5mm / sec. Fig. 4				

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	AEC-Q200 Test Item		Specifi	cations	- AEC-Q200 Test Method			
No.			Temperature Compensating Type	High Dielectric Type				
		Capacitance Change	Within the specified tolerance (Table A)	C7: Withn ±22% (-55°C to +125°C) R7: Withn ±15% (-55°C to +125°C)	The capacitance change should be measured after 5 min. at each specified temperature stage. (1) Temperature Compensating Type The temperature coefficient is determined using the capacitance.			
		Temperature Coefficent	Within the specified tolerance (Table A)		measured in step 3 as a reference. When cycling the temperature sequentially from step1 through 5 (ΔC: +25°C to +125°C: other temp. coeffs.: +25°C to +85°C) the capacitance			
21	Capacitance Temperature Character- istics	Capacitance Drift	Within ±0.2% or ±0.05 pF (Whichever is larger) * Do not apply to 1X/25V		should be within the specified tolerance for the temperature coefficient and capacitance change as shown in Table A. The capacitance drift is calculated by dividing the differences between the maximum and minimum measured values in steps 1, 3 and 5 by the capacitance value in step 3. Step			

Table A

	Nominal Values (ppm/°C) Note1	Capacitance Change from 25°C (%)					
Char.		-55		-30		-10	
		Max.	Min.	Max.	Min.	Max.	Min.
5C	0±30	0.58	-0.24	0.40	-0.17	0.25	-0.11

Note 1: Nominal values denote the temperature coefficient within a range of 25°C to 125°C (for 5C)

^{*1:} The figure indicates typical inspection. Please refer to individual specifications.
*2: Some of the parts are applicable in rated voltage x 150%. Please refer to individual specifications.